**ON Semiconductor** 

Is Now

# Onsemí

To learn more about onsemi<sup>™</sup>, please visit our website at <u>www.onsemi.com</u>

onsemi and ONSEMI. and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product factures, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and asfety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or by customer's technical experts. onsemi products and actal performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use onsemi products for any such unintended or unauthorized application, Buyer shall indemnify and hold onsemi and its officers, employees, subsidiari

# Power MOSFET -40 V, 25 mΩ, -33 A, P-Channel

Automotive Power MOSFET designed for compact and efficient designs and including high thermal performance.

AEC-Q101 qualified MOSFET and PPAP capable suitable for automotive applications.

### Features

- Low On-Resistance
- High Current Capability
- 100% Avalanche Tested
- AEC-Q101 qualified and PPAP capable
- ATPAK package is pin-compatible with DPAK (TO-252)
- Pb-Free, Halogen Free and RoHS compliance

## **Typical Applications**

- Reverse Battery Protection
- Load Switch
- Automotive Front Lighting
- Automotive Body Controllers

#### SPECIFICATIONS

ABSOLUTE MAXIMUM RATING at Ta = 25°C (Note 1)

Parameter	Symbol	Value	Unit
Drain to Source Voltage	VDSS	-40	V
Gate to Source Voltage	VGSS	±20	V
Drain Current (DC)	ID	-33	А
Drain Current (Pulse) PW $\leq 10 \ \mu$ s, duty cycle $\leq 1\%$	IDP	-100	А
Power Dissipation Tc = 25°C	PD	48	W
Operating Junction and Storage Temperature	Tj, Tstg	-55 to +175	°C
Avalanche Energy (Single Pulse) (Note 2)	EAS	30	mJ
Avalanche Current (Note 3)	IAV	-15	А

Note 1 : Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

2 : V\_DD = -10V, L = 200  $\mu H,$  IAV = -15 A

3 : L ≤ 200  $\mu$ H, Single pulse

### THERMAL RESISTANCE RATINGS

Parameter	Symbol	Value	Unit
Junction to Case Steady State (Tc = 25°C)	$R_{\theta JC}$	3.1	°C/W
Junction to Ambient (Note 4)	$R_{\theta}JA$	80.5	°C/W

Note 4 : Surface mounted on FR4 board using a 130 mm<sup>2</sup>, 1 oz. Cu pad.

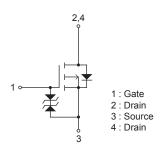


## **ON Semiconductor®**

www.onsemi.com

VDSS	R <sub>DS</sub> (on) Max	ID Max
40.14	25 mΩ @ –10 V	00.4
–40 V	41 mΩ @ –4.5 V	–33 A
40 V	41 mΩ @ –4.5 V	-00 A

## ELECTRICAL CONNECTION P-Channel









## ORDERING INFORMATION

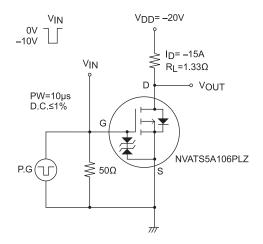
See detailed ordering and shipping information on page 6 of this data sheet.

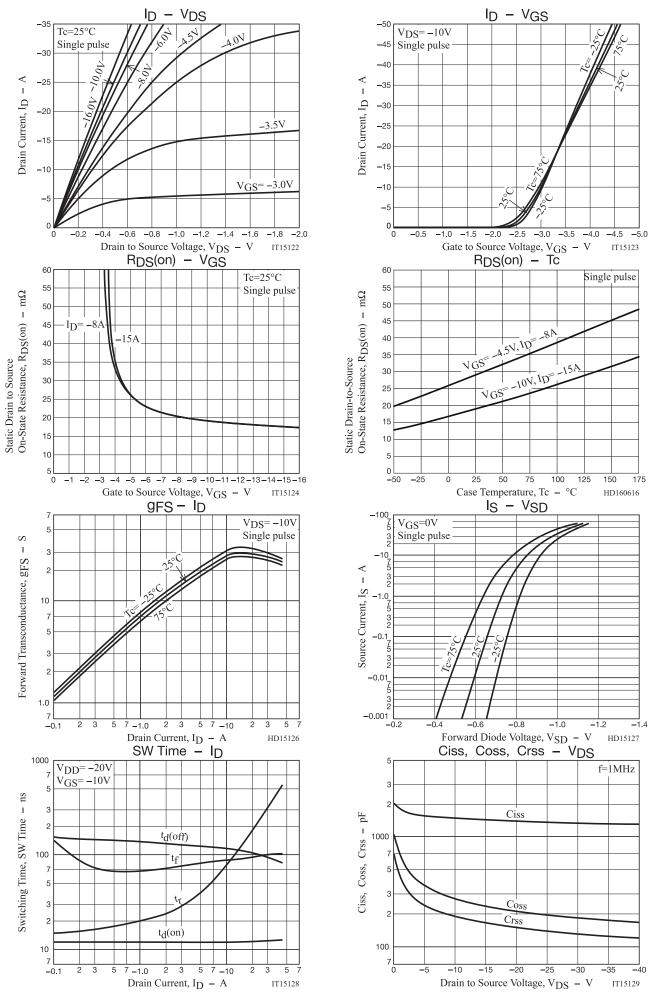
## **ELECTRICAL CHARACTERISTICS** at $Ta = 25^{\circ}C$ (Note 5)

Demonster	C: mah al	Conditions	Value			
Parameter	Symbol	bol Conditions		typ	max	Unit
Drain to Source Breakdown Voltage	V(BR)DSS	ID = -1 mA, VGS = 0 V	-40			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> = -40 V, V <sub>GS</sub> = 0 V			-1	μA
Gate to Source Leakage Current	IGSS	V <sub>GS</sub> = ±16 V, V <sub>DS</sub> = 0 V			±10	μA
Gate Threshold Voltage	VGS(th)	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -1 \text{ mA}$	-1.2		-2.6	V
Forward Transconductance	9FS	V <sub>DS</sub> = -10 V, I <sub>D</sub> = -15 A		28		S
Static Drain to Source On-State Resistance	R <sub>DS</sub> (on)1	I <sub>D</sub> = -15 A, V <sub>GS</sub> = -10 V		19	25	mΩ
	R <sub>DS</sub> (on)2	ID = -8 A, VGS = -4.5 V		29	41	mΩ
Input Capacitance	Ciss			1,380		pF
Output Capacitance	Coss	V <sub>DS</sub> = –20 V, f = 1 MHz		210		pF
Reverse Transfer Capacitance	Crss			150		pF
Turn-ON Delay Time	t <sub>d</sub> (on)			12		ns
Rise Time	tr			120		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	See Fig.1		110		ns
Fall Time	tf			90		ns
Total Gate Charge	Qg			29		nC
Gate to Source Charge	Qgs	$V_{DS}$ = -20 V, $V_{GS}$ = -10 V, $I_{D}$ = -30 A		6.4		nC
Gate to Drain "Miller" Charge	Qgd			5.9		nC
Forward Diode Voltage	VSD	IS = -30 A, VGS = 0 V		-0.97	-1.5	V

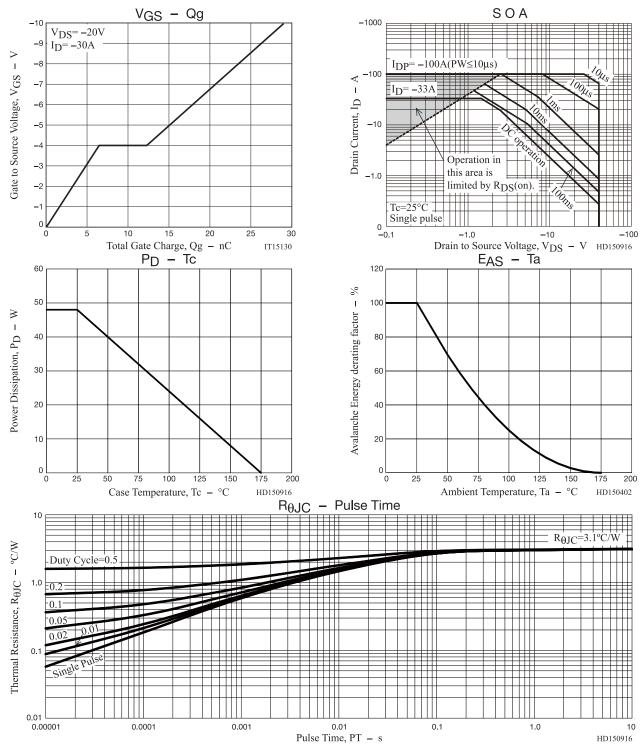
Note 5 : Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

## Fig.1 Switching Time Test Circuit





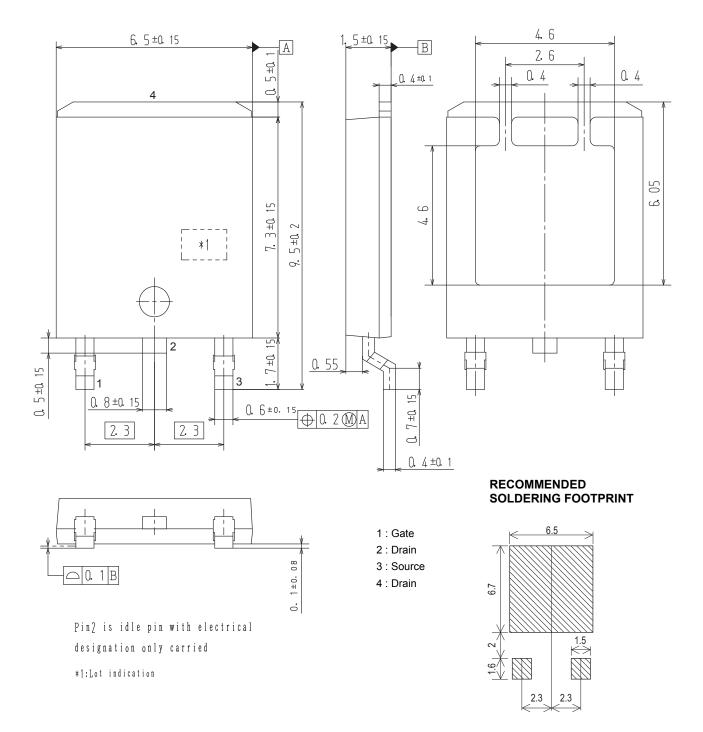
www.onsemi.com 3



#### PACKAGE DIMENSIONS unit : mm

## DPAK (Single Gauge) / ATPAK

CASE 369AM ISSUE O



#### ORDERING INFORMATION

Device	Marking	Package	Shipping (Qty / Packing)
NVATS5A106PLZT4G	ATP106	DPAK(Single Gauge) / ATPAK (Pb-Free / Halogen Free)	3,000 / Tape & Reel

† For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. http://www.onsemi.com/pub\_link/Collateral/BRD8011-D.PDF

Note on usage : Since the NVATS5A106PLZ is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor serves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights or the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, dir